



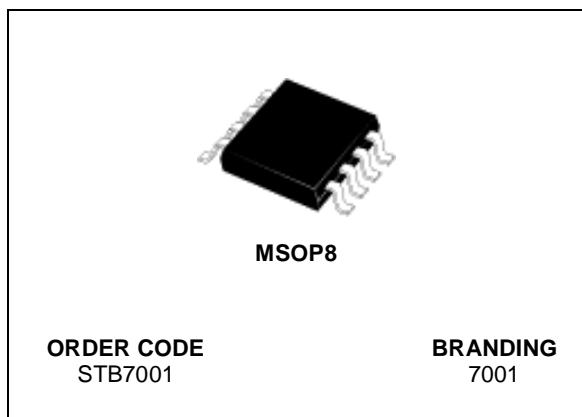
# STB7001

## 900 MHz THREE GAIN LEVEL LNA

- FULLY INTEGRATED 900 MHz LNA
- THREE GAIN LEVELS (0dB, 18dB, 26dB typ. @ 2.8V)
- LOW NOISE FIGURE
- TEMPERATURE COMPENSATED

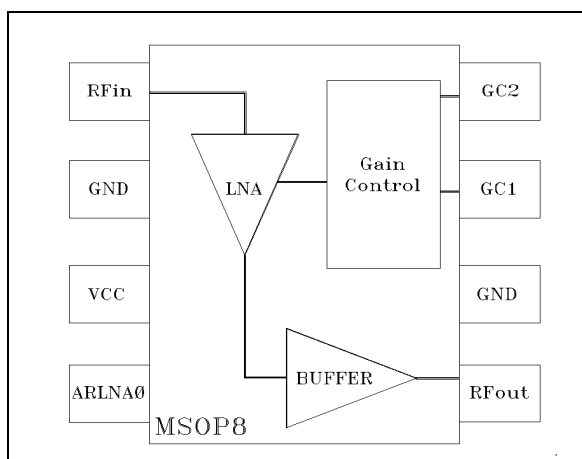
### APPLICATIONS

- GSM HANDSETS



### DESCRIPTION

The STB7001 is a Silicon monolithic amplifier, that offers low noise figure and three gain levels for 900-MHz applications. STB7001 is housed in a small industry-standard MSOP8 surface mount package, requiring very little board space (50% reduction vs SO8 Package). MSOP8 dimensions are 3mmx5mm with a 1.1mm thickness. The device is ESD protected and requires minimum external components in the application circuit, for the on-chip bias and gain control. Furthermore, temperature and supply voltage compensation assures high stability over a wide range of operating conditions.



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>cc</sub>	Supply voltage	5.5	V
T <sub>j</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage temperature	-40 to +85	°C

### THERMAL DATA

Symbol	Parameter	Value	Unit
R <sub>th(j-a)</sub>	Junction -ambient Thermal Resistance	200	°C/W

**ELECTRICAL SPECIFICATION (T<sub>amb</sub> = 25°C, V<sub>cc</sub> = 2.8V)**

Symbol	Parameters	Test Conditions	Min.	Typ.	Max.	Unit
V <sub>cc</sub>	Supply voltage		2.7	2.8	2.9	V
I <sub>bias</sub>	Bias current	for G <sub>p1</sub> <sup>(1)</sup> G <sub>p2</sub> <sup>(1)</sup> G <sub>p3</sub> <sup>(1)</sup>	8 14 10	11.5 17.5 15.0	15.0 22.5 19	mA
I <sub>stby</sub>	Standby current				20	μA
f	Frequency range		925		960	MHz
G <sub>p1,2,3</sub>	Power gain	for G <sub>p1</sub> G <sub>p2</sub> G <sub>p3</sub>	-3.0 16.0 24.0	0.0 18.0 26.0	3.0 20.0 28.0	dB
NF <sub>1,2,3</sub>	Noise figure	for G <sub>p1</sub> G <sub>p2</sub> G <sub>p3</sub>		10 3.1 2.5		dB
P1dB <sub>1,2,3</sub>	Input 1 dB Compr.Power	for G <sub>p1</sub> G <sub>p2</sub> G <sub>p3</sub>		-15.0 -19.0 -26.5		dBm
IIP3 <sub>1,2,3</sub>	Input Third Order Intercept	for G <sub>p1</sub> G <sub>p2</sub> G <sub>p3</sub>		-6.0 -11.0 -20.0		dBm
VSWR <sub>i</sub>	Input VSWR				1.5:1	
VSWR <sub>o</sub>	Output VSWR				1.5:1	
AZout	Zout LNA on/off				15	%

Note(1) : G<sub>p1</sub> min gain, G<sub>p2</sub> mid gain and G<sub>p3</sub> max gain.

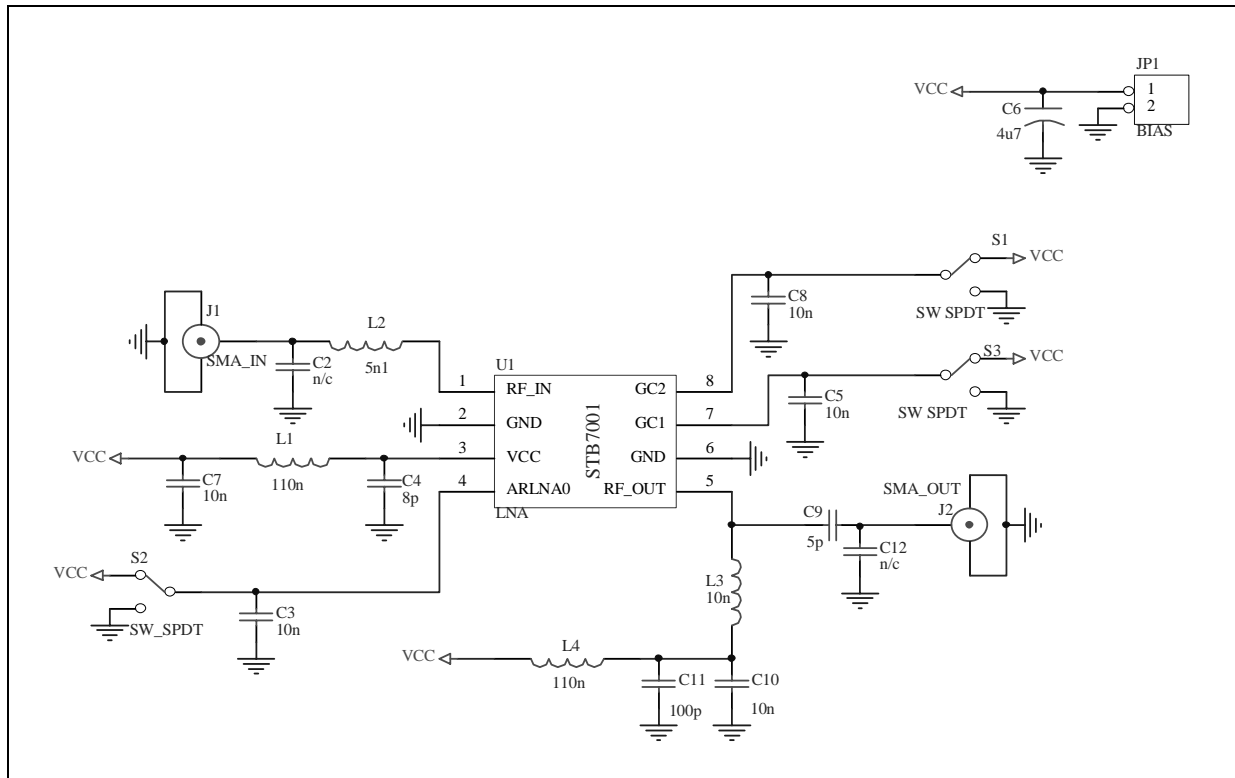
**PINOUT**

Pin Number	Symbol	Description	Evaluation circuit components
1	RFin	RF input	L2 = 5.1nH, C2 = n/c
2	Gnd	Ground	
3	Vcc	Voltage supply	C4 = 8pF, L1 = 110nH, C7 = 10nF, C6 = 4.7uF
4	ARLNA0	Enable for power down	C3 = 10nF
5	RFout	RF output	C9 = 5pf, L3 = 10nH, C10 = 10nF, C11 = 100pF, L4 = 110nH
6	Gnd	Ground	
7	GC1	Gain selection	C5 = 10nF
8	GC2	Gain selection	C8 = 10nF

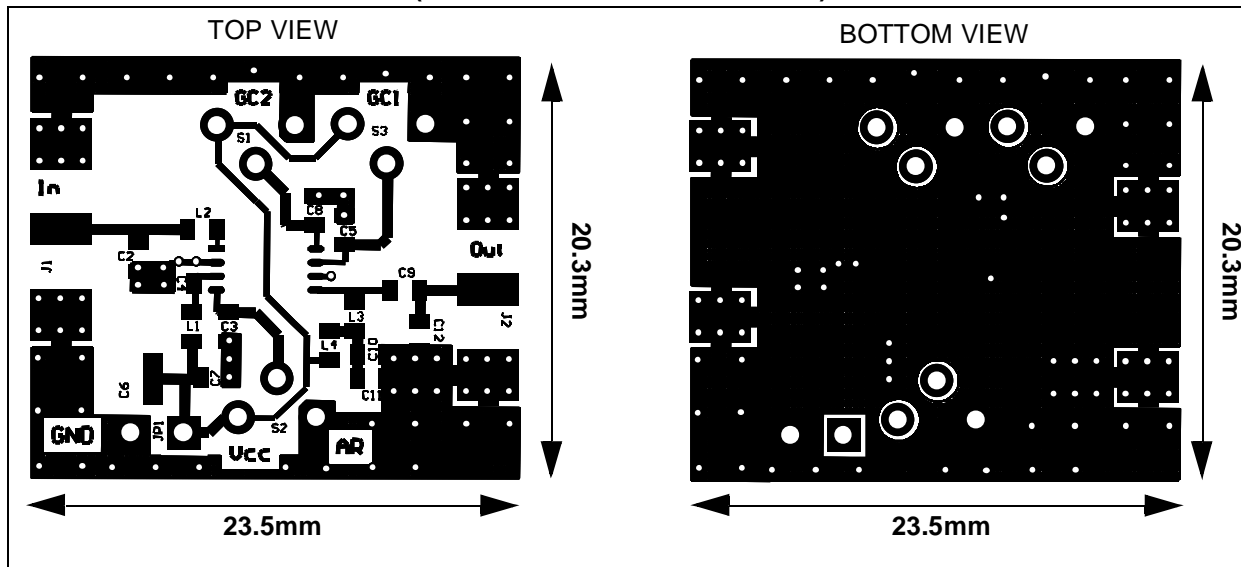
**GAIN SELECTION**

	G <sub>p1</sub>	G <sub>p2</sub>	G <sub>p3</sub>
GC1	0	0	1
GC2	0	1	1

## TEST CIRCUIT SCHEMATIC



## TEST CIRCUIT PHOTOMASTER (board dimention 23.5x20.3mm)



**INPUT/OUTPUT VSWR, ISOLATION AND GAIN PARAMETERS (MEASURED DATA)****MAX GAIN**

Freq.	VSWRi	VSWRo	Isolation	Gain
905	1.16	1.15	-43.61	25.09
912.5	1.15	1.17	-45.69	25.04
913.5	1.15	1.17	-42.84	24.98
927.5	1.15	1.17	-43.36	24.92
935	1.14	1.18	-42.42	24.85
942.5	1.14	1.19	-48.58	24.79
950	1.14	1.20	-47.86	24.72
957.5	1.13	1.18	-41.52	24.68
965	1.13	1.19	-45.53	24.61
972.5	1.14	1.22	-49.18	24.57
980	1.13	1.20	-44.99	24.48
987.5	1.14	1.21	-47.83	24.41
995	1.14	1.21	-45.33	24.35

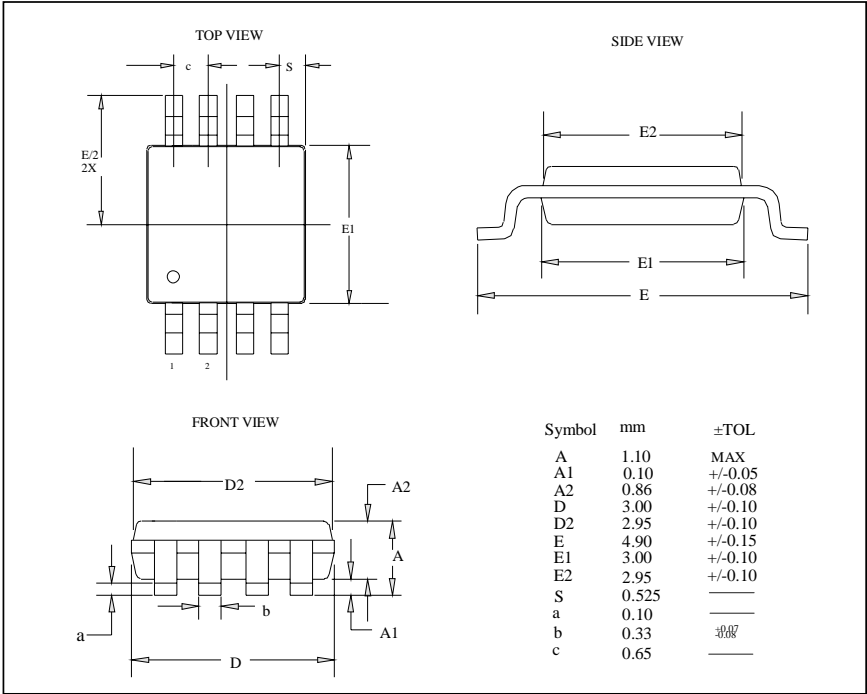
**MID GAIN**

Freq.	VSWRi	VSWRo	Isolation	Gain
905	1.18	1.10	-44.66	17.41
912.5	1.18	1.11	-43.96	17.36
913.5	1.18	1.11	-46.54	17.32
927.5	1.18	1.12	-46.48	17.28
935	1.18	1.12	-46.39	17.25
942.5	1.18	1.13	-48.29	17.19
950	1.18	1.13	-47.05	17.16
957.5	1.19	1.13	-48.72	17.11
965	1.20	1.14	-50.07	17.07
972.5	1.20	1.14	-50.48	17.02
980	1.21	1.15	-55.86	16.96
987.5	1.22	1.15	-52.12	16.92
995	1.23	1.15	-56.92	16.86

**MIN GAIN**

<b>Freq.</b>	<b>VSWRi</b>	<b>VSWRo</b>	<b>Isolation</b>	<b>Gain</b>
<b>905</b>	1.54	1.11	-43.83	0.07
<b>912.5</b>	1.54	1.11	-43.63	0.03
<b>913.5</b>	1.54	1.12	-45.88	-0.04
<b>927.5</b>	1.54	1.13	-45.76	-0.10
<b>935</b>	1.55	1.13	-45.69	-0.13
<b>942.5</b>	1.56	1.14	-46.75	-0.21
<b>950</b>	1.56	1.14	-45.29	-0.27
<b>957.5</b>	1.57	1.14	-45.20	-0.34
<b>965</b>	1.59	1.15	-45.38	-0.41
<b>972.5</b>	1.60	1.15	-45.79	-0.48
<b>980</b>	1.61	1.16	-45.15	-0.59
<b>987.5</b>	1.61	1.17	-42.79	-0.67
<b>995</b>	1.60	1.17	-43.49	-0.77

MSOP8 MECHANICAL DATA



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